

Descriptions

- General purpose application
- Switching application

Features

• High voltage : $V_{CEO} = -45V$

• Complementary pair with BC847

Ordering Information

Type NO.	Marking	Package Code		
BC857	UA□	SOT-23		
Outline Dimensions	☐ : h _{FE} rank	A STATE OF THE STA	unit: mm	
	2.4±0.1 1.30±0.1 1 2 2 2 2 2 2 2 4 0 0 1 1 1 1 1 1 1 1 1 1 1 1 1	2.9±0.1		
	1.12 Max. 0.38 0~0.1	0.2 Min. PIN Co 1. Base 2. Emit 3. Colle	ter	

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Absolute maximum ratings

(Ta=25°C)

Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	V_{CBO}	-50	V
Collector-Emitter voltage	$V_{\sf CEO}$	-45	V
Emitter-Base voltage	V_{EBO}	-5	V
Collector current	I _c	-100	mA
Collector dissipation	P _C	200	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55~150	°C

Electrical Characteristics

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Emitter breakdown voltage	BV _{CEO}	$I_C=-2mA$, $I_B=0$	-45	-	-	V
Base -Emitter turn on voltage	V _{BE(ON)}	V_{CE} =-5V, I_{C} =-2mA	-	-	-700	mV
Base -Emitter saturation voltage	$V_{BE(sat)}$	I_{c} =-100mA, I_{B} =-5mA	-	-900	-	mV
Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_{c} = -100 \text{mA}, I_{B} = -5 \text{mA}$	-	-	-650	mV
Collector cut-off current	I _{CBO}	$V_{CB} = -35V$, $I_{E} = 0$	10	-	-15	nA
DC current gain	h _{FE} *	$V_{CE}=-5V$, $I_{C}=-2mA$	110	-	800	-
Transition frequency	f _T	V_{CB} =-5V, I_{C} =-10mA	-	150	-	MHz
Collector output capacitance	C _{ob}	$V_{CB} = -10V$, $I_{E} = 0$, $f = 1MHz$	-	-	4.5	pF
Noise Figure	NF	V_{CE} =-5V, I_{C} =-200μA, f=1KHz,Rg=2K Ω	-	-	10	dB

^{* :} h_{FE} rank / A : 110 ~ 220, B : 200 ~ 450, C : 420 ~ 800

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Electrical Characteristic Curves



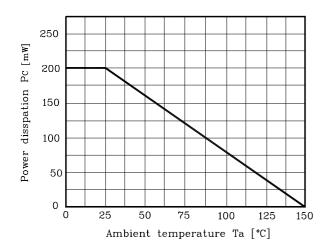


Fig. 2 I_{C} - V_{BE}

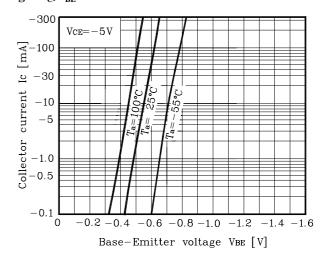


Fig. 3 $I_{C}V_{CE}$

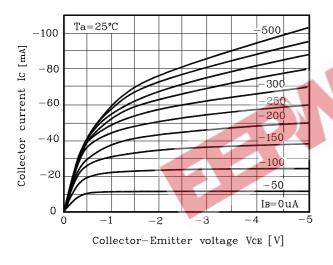


Fig. 4 h_{FE} - I_{C}

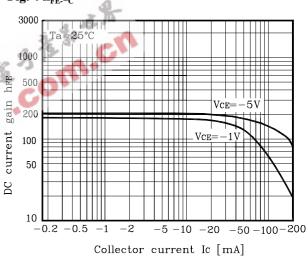
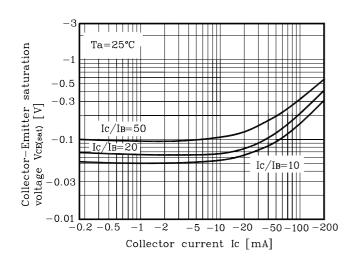


Fig. 5 $V_{\text{CE(sat)}}$ - I_{C}



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